

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application)	<u>PATENT APPLICATION</u>
)	
Inventor:	Jian Chen, et al.)
)	
Application No.:	10/765,693)
)	Art Unit: 2824
Filed Date:	January 26, 2004)
)	Examiner: Tran, Andrew Q.
Title: METHOD OF READING NAND MEMORY) TO COMPENSATE FOR COUPLING BETWEEN) STORAGE ELEMENTS)	<u>Customer No.: 64948</u>
)	

RESPONSE C TO OFFICE ACTION UNDER 37 C.F.R. § 1.116

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This RESPONSE C is in reply to the Office Action mailed June 11, 2007 and the Advisory Action mailed September 25, 2007.

RESPONSE B, submitted September 11, 2007, is hereby withdrawn.

AMENDMENTS TO THE CLAIMS are reflected in the listing of claims which begin on page 2 of this Response.

AMENDMENTS TO THE ABSTRACT are reflected in the listing of claims which begin on page 6 of this Response.

REMARKS begin on Page 7 of this Response.